Darlington Transistors

NPN Silicon

Features

• Pb–Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CES}	20	Vdc
Emitter Base Voltage	V _{EBO}	10	Vdc
Total Device Dissipation @ $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	PD	625 5.0	mW mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

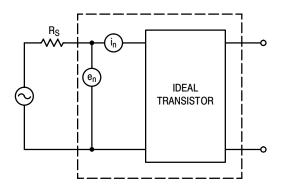
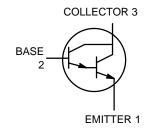


Figure 1. Transistor Noise Model

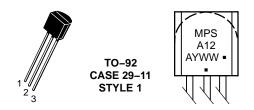


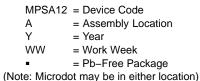
ON Semiconductor®

http://onsemi.com









Note. Microdot may be in ether location

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSA12	TO-92	5,000 Units/Box
MPSA12G	TO–92 (Pb–Free)	5,000 Units/Box
MPSA12RLRA	TO-92	2,000/Tape & Reel
MPSA12RLRAG	TO–92 (Pb–Free)	2,000/Tape & Reel
MPSA12RLRP	TO-92	2,000/Tape & Reel
MPSA12RLRPG	TO-92 (Pb-Free)	2,000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MPSA12

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

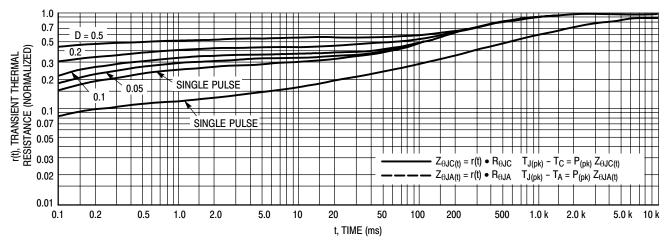
Base – Emitter On Voltage ($I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_C = 100 \ \mu Adc, I_B = 0)$	V _{(BR)CES}	20	-	Vdc
Collector Cutoff Current (V_{CB} = 15 Vdc, I _E = 0)	I _{CBO}	-	100	nAdc
Emitter Cutoff Current (V_{EB} = 12 Vdc, I _C = 0)	I _{EBO}	-	100	nAdc
ON CHARACTERISTICS				
DC Current Gain (I _C = 10 mAdc, V _{CE} = 5.0 Vdc)	h _{FE}	20,000	_	-
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 0.01 \text{ mAdc}$)	V _{CE(sat)}	-	1.0	Vdc

V_{BE(on)}

1.4

Vdc

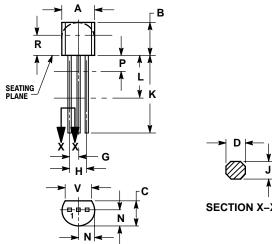




MPSA12

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**







NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982.
- 2
- TI4-3M, 1962. CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND 3.
- 4. BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Η	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
۷	0.135		3.43	

STYLE 1: PIN 1. EMITTER

BASE 2. 3.

COLLECTOR

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